

TC7MET138AFK

3-to-8 Line Decoder

The TC7MET138AFK is an advanced high speed CMOS 3-to-8 line decoder fabricated with silicon gate C²MOS technology. It achieves the high speed operation similar to equivalent bipolar schottky TTL while maintaining the CMOS low power dissipation.

When the device is enabled, 3 binary select inputs (A, B and C) determine which one of the outputs ($\overline{Y}0 - \overline{Y}7$) will go low.

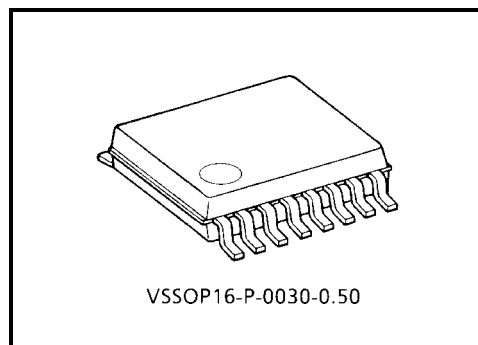
When enable input G1 is held low or either $\overline{G}2A$ or $\overline{G}2B$ is held high, decoding function is inhibited and all outputs go high. G1, $\overline{G}2A$, and $\overline{G}2B$ inputs are provided to ease cascade connection and for use as an address decoder for memory systems.

The input voltage are compatible with TTL output voltage.

This device may be used as a level converter for interfacing 3.3 V to 5 V system.

Input protection and output circuit ensure that 0 to 5.5 V can be applied to the input and output (*) pins without regard to the supply voltage. These structure prevents device destruction due to mismatched supply and input/output voltages such as battery back up, hot board insertion, etc.

*: $V_{CC} = 0\text{ V}$

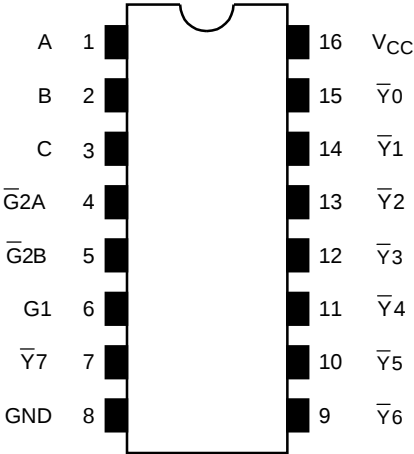


Weight: 0.02 g (typ.)

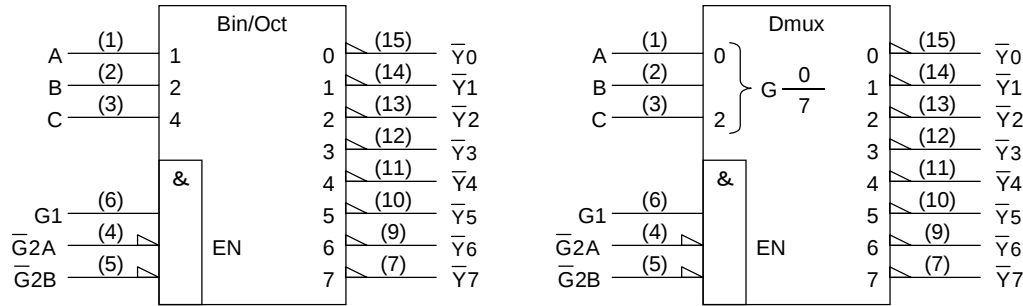
Features

- High speed: $t_{pd} = 7.6\text{ ns}$ (typ.) ($V_{CC} = 5\text{ V}$)
- Low power dissipation: $I_{CC} = 4\text{ }\mu\text{A}$ (max) ($T_a = 25^\circ\text{C}$)
- Compatible with TTL outputs: $V_{IL} = 0.8\text{ V}$ (max)
 $V_{IH} = 2.0\text{ V}$ (min)
- Power down protection is provided on all inputs and outputs.
- Balanced propagation delays: $t_{pLH} \approx t_{pHL}$
- Pin and function compatible with the 74 series (74AC/HC/ALS/LS etc.) 138 type.

Pin Assignment (top view)



IEC Logic Symbol

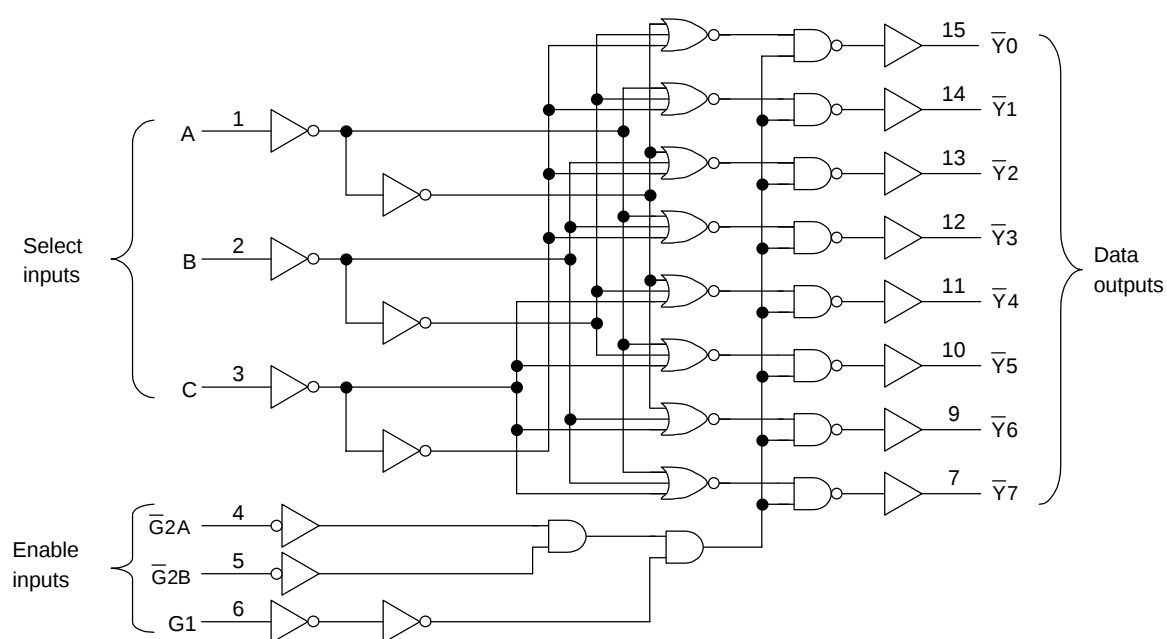


Truth Table

Inputs						Outputs								Selected Output
Enable			Select			$\overline{Y}0$	$\overline{Y}1$	$\overline{Y}2$	$\overline{Y}3$	$\overline{Y}4$	$\overline{Y}5$	$\overline{Y}6$	$\overline{Y}7$	
G1	$\overline{G}2A$	$\overline{G}2B$	C	B	A									
L	X	X	X	X	X	H	H	H	H	H	H	H	H	None
X	H	X	X	X	X	H	H	H	H	H	H	H	H	None
X	X	H	X	X	X	H	H	H	H	H	H	H	H	None
H	L	L	L	L	L	L	H	H	H	H	H	H	H	$\overline{Y}0$
H	L	L	L	L	H	H	L	H	H	H	H	H	H	$\overline{Y}1$
H	L	L	L	H	L	H	H	L	H	H	H	H	H	$\overline{Y}2$
H	L	L	L	H	H	H	H	H	L	H	H	H	H	$\overline{Y}3$
H	L	L	H	L	L	H	H	H	H	L	H	H	H	$\overline{Y}4$
H	L	L	H	L	H	H	H	H	H	H	L	H	H	$\overline{Y}5$
H	L	L	H	H	L	H	H	H	H	H	H	L	H	$\overline{Y}6$
H	L	L	H	H	H	H	H	H	H	H	H	H	L	$\overline{Y}7$

X: Don't care

System Diagram



Maximum Ratings

Characteristics	Symbol	Rating	Unit
Supply voltage range	V_{CC}	-0.5~7.0	V
DC input voltage	V_{IN}	-0.5~7.0	V
DC output voltage	V_{OUT}	-0.5~7.0 (Note1)	V
		-0.5~ $V_{CC} + 0.5$ (Note2)	
Input diode current	I_{IK}	-20	mA
Output diode current	I_{OK}	± 20 (Note3)	mA
DC output current	I_{OUT}	± 25	mA
DC V_{CC} /ground current	I_{CC}	± 75	mA
Power dissipation	P_D	180	mW
Storage temperature	T_{stg}	-65~150	°C

Note1: $V_{CC} = 0$ V

Note2: High or low state. I_{OUT} absolute maximum rating must be observed.

Note3: $V_{OUT} < GND$, $V_{OUT} > V_{CC}$

Recommended Operating Conditions

Characteristics	Symbol	Rating	Unit
Supply voltage	V_{CC}	4.5~5.5	V
Input voltage	V_{IN}	0~5.5	V
Output voltage	V_{OUT}	0~5.5 (Note4)	V
		0~ V_{CC} (Note5)	
Operating temperature	T_{opr}	-40~85	°C
Input rise and fall time	dt/dv	0~20	ns/V

Note4: $V_{CC} = 0$ V

Note5: High or low state.

Electrical Characteristics

DC Characteristics

Characteristics		Symbol	Test Condition		Ta = 25°C			Ta = -40~85°C		Unit	
					V _{CC} (V)	Min	Typ.	Max	Min		Max
Input voltage	High level	V _{IH}	—		4.5~5.5	2.0	—	—	2.0	—	V
	Low level	V _{IL}	—		4.5~5.5	—	—	0.8	—	0.8	
Output voltage	High level	V _{OH}	V _{IN} = V _{IH} or V _{IL}	I _{OH} = -50 μA	4.5	4.4	4.5	—	4.4	—	V
				I _{OH} = -8 mA	4.5	3.94	—	—	3.80	—	
	Low level	V _{OL}	V _{IN} = V _{IH} or V _{IL}	I _{OL} = 50 μA	4.5	—	0	0.1	—	0.1	
				I _{OL} = 8 mA	4.5	—	—	0.36	—	0.44	
Input leakage current		I _{IN}	V _{IN} = 5.5 V or GND		0~5.5	—	—	±0.1	—	±1.0	μA
Quiescent supply current		I _{CC}	V _{IN} = V _{CC} or GND		5.5	—	—	4.0	—	40.0	μA
		I _{CC} T	Per input: V _{IN} = 3.4 V Other input: V _{CC} or GND		5.5	—	—	1.35	—	1.50	mA
Output leakage current		I _{OPD}	V _{OUT} = 5.5 V		0	—	—	0.5	—	5.0	μA

AC Characteristics (Input: $t_r = t_f = 3 \text{ ns}$)

Characteristics	Symbol	Test Condition			Ta = 25°C			Ta = -40~85°C		Unit
			V _{CC} (V)	C _L (pF)	Min	Typ.	Max	Min	Max	
Propagation delay time (A, B, C- $\bar{Y}$)	t _{pLH} t _{pHL}	—	5.0 ± 0.5	15	—	7.6	10.4	1.0	12.0	ns
				50	—	8.1	11.4	1.0	13.0	
Propagation delay time (G1- $\bar{Y}$)	t _{pLH} t _{pHL}	—	5.0 ± 0.5	15	—	6.6	9.1	1.0	10.5	ns
				50	—	7.1	10.1	1.0	11.5	
Propagation delay time ($\bar{G}2$ - $\bar{Y}$)	t _{pLH} t _{pHL}	—	5.0 ± 0.5	15	—	7.0	9.6	1.0	11.0	ns
				50	—	7.5	10.6	1.0	12.0	
Input capacitance	C _{IN}	—			—	4	10	—	10	pF
Power dissipation capacitance	C _{PD}	(Note6)			—	49	—	—	—	pF

Note6: C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load.

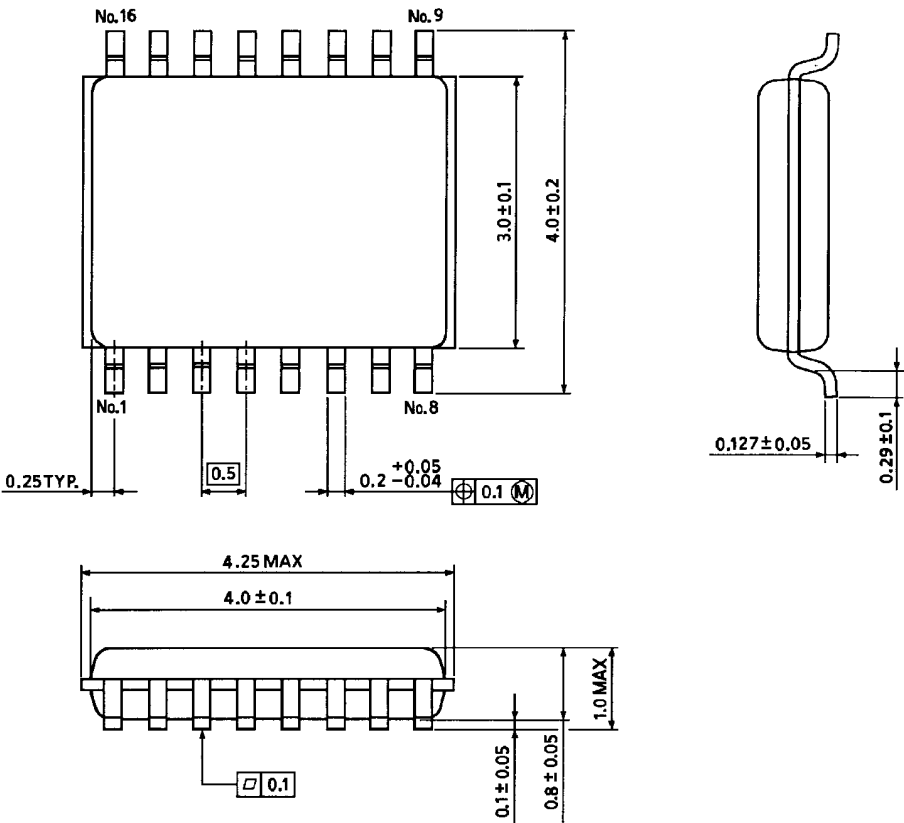
Average operating current can be obtained by the equation:

$$I_{CC} (opr) = C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC}$$

Package Dimensions

VSSOP16-P-0030-0.50

Unit : mm



Weight: 0.02 g (typ.)

RESTRICTIONS ON PRODUCT USE

000707EBA

- TOSHIBA is continually working to improve the quality and reliability of its products. Nevertheless, semiconductor devices in general can malfunction or fail due to their inherent electrical sensitivity and vulnerability to physical stress. It is the responsibility of the buyer, when utilizing TOSHIBA products, to comply with the standards of safety in making a safe design for the entire system, and to avoid situations in which a malfunction or failure of such TOSHIBA products could cause loss of human life, bodily injury or damage to property.
In developing your designs, please ensure that TOSHIBA products are used within specified operating ranges as set forth in the most recent TOSHIBA products specifications. Also, please keep in mind the precautions and conditions set forth in the "Handling Guide for Semiconductor Devices," or "TOSHIBA Semiconductor Reliability Handbook" etc..
- The TOSHIBA products listed in this document are intended for usage in general electronics applications (computer, personal equipment, office equipment, measuring equipment, industrial robotics, domestic appliances, etc.). These TOSHIBA products are neither intended nor warranted for usage in equipment that requires extraordinarily high quality and/or reliability or a malfunction or failure of which may cause loss of human life or bodily injury ("Unintended Usage"). Unintended Usage include atomic energy control instruments, airplane or spaceship instruments, transportation instruments, traffic signal instruments, combustion control instruments, medical instruments, all types of safety devices, etc.. Unintended Usage of TOSHIBA products listed in this document shall be made at the customer's own risk.
- The products described in this document are subject to the foreign exchange and foreign trade laws.
- The information contained herein is presented only as a guide for the applications of our products. No responsibility is assumed by TOSHIBA CORPORATION for any infringements of intellectual property or other rights of the third parties which may result from its use. No license is granted by implication or otherwise under any intellectual property or other rights of TOSHIBA CORPORATION or others.
- The information contained herein is subject to change without notice.